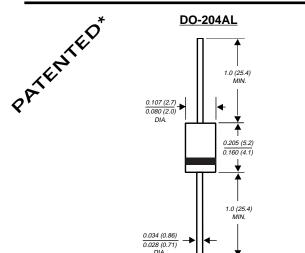
1N4001GP THRU 1N4007GP

GLASS PASSIVATED JUNCTION RECTIFIER

Reverse Voltage - 50 to 1000 Volts

Forward Current - 1.0 Ampere



Dimensions in inches and (millimeters)

* Glass-plastic encapsulation technique is covered by
Patent No. 3,996,602 and brazed-lead assembly by Patent No. 3,930,306



FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- High temperature metallurgically bonded construction
- ♦ Glass passivated cavity-free junction
- Capable of meeting environmental standards of MIL-S-19500
- ◆ 1.0 Ampere operation at TA=75°C with no thermal runaway
- ♦ Typical IR less than 0.1μA
- ◆ High temperature soldering guaranteed: 350°C/10 seconds, 0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension

MECHANICAL DATA

Case: JEDEC DO-204AL molded plastic over glass body **Terminals:** Plated axial leads, solderable per MIL-STD-750,

Method 2026

Polarity: Color band denotes cathode end

Mounting Position: Any **Weight:** 0.012 ounce, 0.3 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

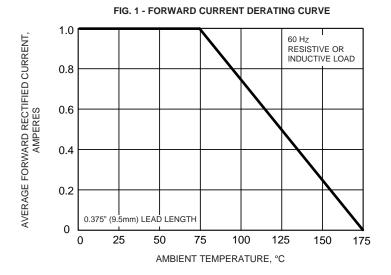
	SYMBOLS	1N 4001GP	1N 4002GP	1N 4003GP	1N 4004GP	1N 4005GP	1N 4006GP	1N 4007GP	UNITS
* Maximum repetitive peak reverse voltage	VRRM	50	100	200	400	600	800	1000	Volts
* Maximum RMS voltage	VRMS	35	70	140	280	420	560	700	Volts
* Maximum DC blocking voltage	VDC	50	100	200	400	600	800	1000	Volts
* Maximum average forward rectified current 0.375" (9.5mm) lead length at Ta=75°C	I _(AV)				1.0				Amp
* Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	IFSM				30.0				Amps
Maximum instantaneous forward voltage at 1.	0A VF				1.1				Volts
* Maximum full load reverse current, full cycle average 0.375" (9.5mm) lead length TA= 75°	C I _{R(AV)}				30.0				μА
* Maximum DC reverse current at rated DC blocking voltage TA=25°C	· I ID	5.0 50.0						μА	
Typical reverse recovery time (NOTE 1)	trr				2.0				μs
Typical junction capacitance (NOTE 2)	CJ				8.0				pF
Typical thermal resistance (NOTE 3)	R⊕JA R⊕JL				55.0 25.0				°C/W
* Operating junction and storage temperature ra	ange TJ, TsTG				-65 to +1	75			°C

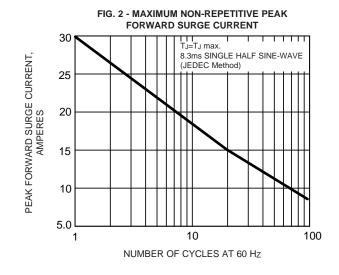
NOTES

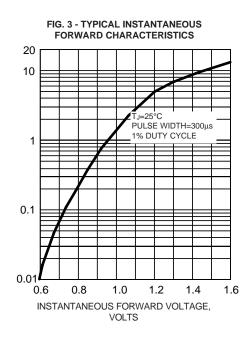
- (1) Reverse recovery test conditions: I_F=0.5A, I_R=1.0A, I_{rr}= 0.25A
- (2) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts
- (a) Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted *JEDEC registered values



RATINGS AND CHARACTERISTIC CURVES 1N4001GP THRU 1N4007GP







INSTANTANEOUS FORWARD CURRENT, AMPERES

